





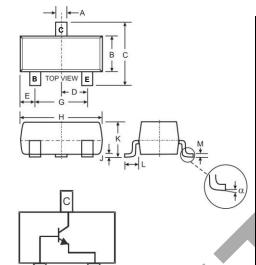
### NPN SURFACE MOUNT VHF/UHF TRANSISTOR

#### **Features**

- Designed for VHF/UHF Amplifier Applications and High Output VHF Oscillators
- High Current Gain Bandwidth Product
- Ideal for Mixer and RF Amplifier Applications with collector currents in the 100μA - 30 mA Range
- Lead, Halogen and Antimony Free, RoHS Compliant "Green" Device (Notes 3 and 4)

#### **Mechanical Data**

- Case: SOT-23
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Marking Information: See Page 3
- Ordering Information: See Page 3
- Weight: 0.008 grams (approximate)



1										
SOT-23										
Dim	Min	Max								
Α	0.37	0.51								
В	1.20	1.40								
C	2.30	2.50								
D	0.89	1.03								
E	0.45	0.60								
G	1.78	2.05								
Н	2.80	3.00								
J	0.013	0.10								
K	0.903	1.10								
L	0.45	0.61								
М	0.085	0.180								
α	0°	8°								
All Dimensions in mm										

## **Maximum Ratings** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	40	V
Collector-Emitter Voltage	$V_{\sf CEO}$	40	V
Emitter-Base Voltage	V <sub>EBO</sub>	4.0	V
Collector Current - Continuous (Note 1)	Ic	50	mA
Power Dissipation (Note 1)	P <sub>d</sub>	300	mW
Thermal Resistance, Junction to Ambient (Note 1)	$R_{ heta JA}$	417	°C/W
Operating and Storage Temperature Range	T <sub>i</sub> , T <sub>STG</sub>	-55 to +150	°C

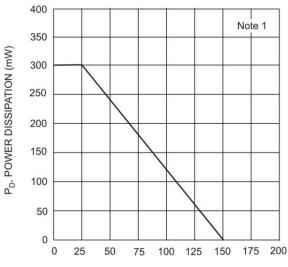
## Electrical Characteristics @TA = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition					
OFF CHARACTERISTICS (Note 2)										
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	40	_	V	$I_C = 1 \text{mA}, I_B = 0$					
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	40	_	V	$I_C = 100 \mu A, I_E = 0$					
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	4.0	_	V	$I_E = 10 \mu A, I_C = 0$					
Collector Cutoff Current	I <sub>CBO</sub>	_	100	nA	$V_{CB} = 30V, I_{E} = 0$					
Emitter Cutoff Current	I <sub>EBO</sub>	_	100	nA	V <sub>EB</sub> = 2V, I <sub>C</sub> = 0					
ON CHARACTERISTICS (Note 2)										
DC Current Gain	h <sub>FE</sub>	30	_	_	$I_C = 8mA, V_{CE} = 10.0V$					
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>	_	0.5	V	$I_C = 4mA, I_B = 400\mu A$					
Base-Emitter On Voltage	V <sub>BE(SAT)</sub>	_	0.95	V	$I_C = 4mA, V_{CE} = 10.0V$					
SMALL SIGNAL CHARACTERISTICS										
Current Gain-Bandwidth Product	f <sub>T</sub>	400	_	MHz	V <sub>CE</sub> = 10V, f = 100MHz, I <sub>C</sub> = 8mA					
Collector-Base Capacitance	ССВ	_	0.7	pF	V <sub>CB</sub> = 10V, f = 1.0MHz, I <sub>E</sub> = 0					
Collector-Base Feedback Capacitance	C <sub>RB</sub>	_	0.65	pF	V <sub>CB</sub> = 10V, f = 1.0MHz, I <sub>E</sub> = 0					
Collector-Base Time Constant	Rb'Cc	_	9	ps	I <sub>C</sub> = 4mA, V <sub>CB</sub> = 10V, f = 31.8MHz					

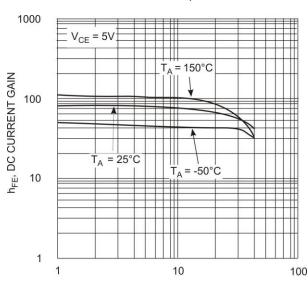
Notes: 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch pad layout, as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

- 2. Short duration pulse test used to minimize self-heating effect.
- 3. No purposefully added lead. Halogen and Antimony Free.
- Product manufactured with Data Code V9 (week 33, 2008) and newer are built with Green Molding Compound. Product manufactured prior to Date Code V9 are built with Non-Green Molding Compound and may contain Halogens or Sb₂O₃ Fire Retardants.

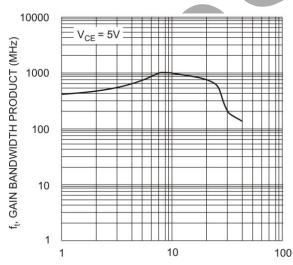




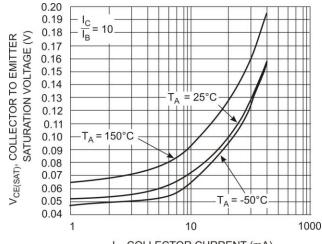
T<sub>A</sub>, AMBIENT TEMPERATURE (°C) Fig. 1, Max Power Dissipation vs Ambient Temperature



I<sub>C</sub>, COLLECTOR CURRENT (mA) Fig. 3, DC Current Gain vs. Collector Current



I<sub>C</sub>, COLLECTOR CURRENT (mA)
Fig. 5, Gain Bandwidth Product vs Collector Current



I<sub>C</sub>, COLLECTOR CURRENT (mA) Fig. 2 Collector Emitter Saturation Voltage vs. Collector Current

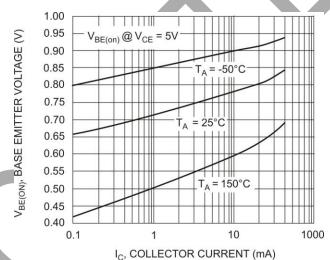


Fig. 4 Base Emitter Voltage vs. Collector Current

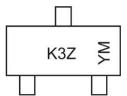


# Ordering Information (Note 5)

Device	Packaging	Shipping			
MMBTH24-7-F	SOT-23	3000/Tape & Reel			

5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

# **Marking Information**



K3Z = Product Type Marking Code

YM = Date Code Marking Y = Year ex: N = 2002 M = Month ex: 9 = September

Date Code	Key													
Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009 20	201	2012
Code	J	K	L	М	N	Р	R	S	Т	U	V	W	X Y	Z
Month	Jan	Fe	b	Mar	Apr	May	Ju	n	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2		3	4	5	6		7	8	9	0	N	D





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